

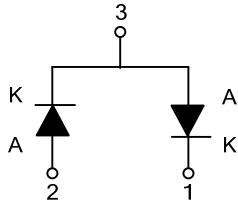


BAV99

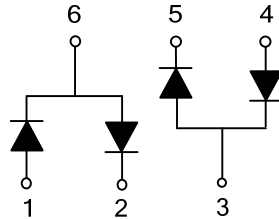
DIODE

HIGH CONDUCTANCE ULTRA FAST DIODE

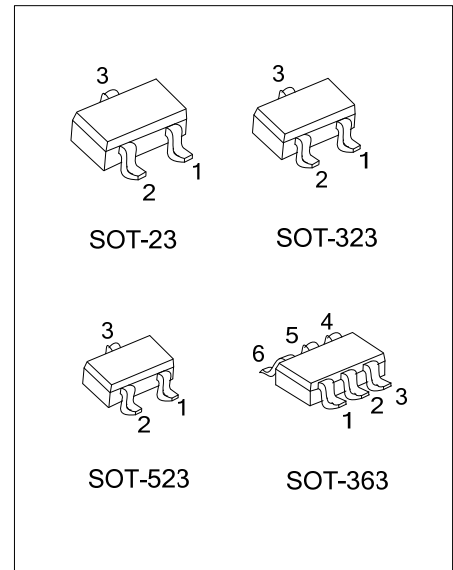
■ EQUIVALENT



For 3 Pin Package



For 6 Pin Package



■ ORDERING INFORMATION

Ordering Number	Package	Pin Assignment						Packing
		1	2	3	4	5	6	
BAV99G-AE3-R	SOT-23	K1	A2	K2A1	-	-	-	Tape Reel
BAV99G-AL3-R	SOT-323	K1	A2	K2A1	-	-	-	Tape Reel
BAV99G-AN3-R	SOT-523	K1	A2	K2A1	-	-	-	Tape Reel
BAV99G-AL6-R	SOT-363	A1	K1	A2K2	A2	K2	A1K1	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

<p>BAV99G-AE3-R</p>	<p>(1) R: Tape Reel (2) AE3: SOT-23, AL3: SOT-523, AN3: SOT-523, AL6: SOT-363 (3) G: Halogen Free and Lead Free</p>
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■ MARKING

SOT-23 / SOT-323 / SOT-523	SOT-363

■ ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	RATINGS	UNIT	
Working Inverse Voltage	W_{IV}	70	V	
Average Rectified Current	$I_{F(AV)}$	200	mA	
DC Forward Current	I_{FM}	600	mA	
Recurrent Peak Forward Current	I_{FRM}	700	mA	
Non-repetitive Peak Forward Surge Current		Pulse width = 1.0 second	1.0	A
		Pulse width = 1.0 microsecond	2.0	A
Power Dissipation	P_D	SOT-23	350	mW
		SOT-523	150	mW
		SOT-323/SOT-363	200	mW
Junction Temperature	T_J	+150	$^\circ\text{C}$	
Storage Temperature	T_{STG}	-65 ~ +150	$^\circ\text{C}$	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

■ THERMAL DATA

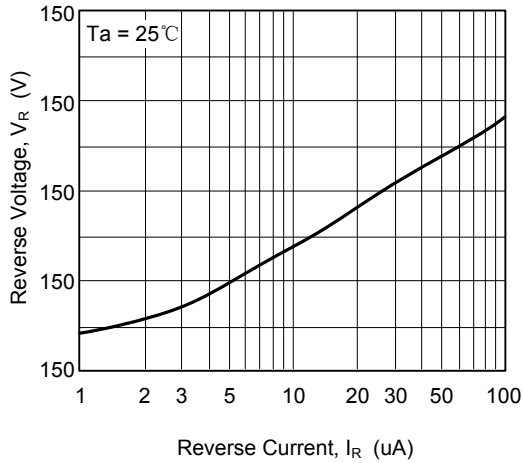
PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	SOT-23	357	$^\circ\text{C}/\text{W}$
		SOT-523	833	$^\circ\text{C}/\text{W}$
		SOT-323/SOT-363	625	$^\circ\text{C}/\text{W}$

■ ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified.)

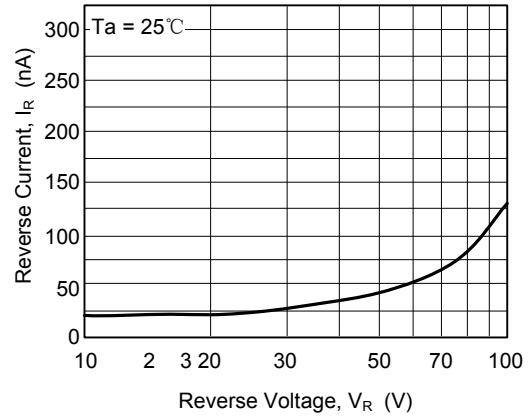
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Breakdown Voltage	V_R	$I_R = 100\mu\text{A}$	70			V
Maximum Instantaneous Forward Voltage	V_{FM}	$I_F = 1.0\text{mA}$			775	mV
		$I_F = 10\text{mA}$			855	mV
		$I_F = 50\text{mA}$			1.0	V
		$I_F = 150\text{mA}$			1.25	V
Peak Forward Voltage	V_{SM}	$I_F = 10\text{mA}$, $t_R = 20\text{nS}$			1.75	V
Maximum Instantaneous Reverse Current	I_{RM}	$V_R = 70\text{V}$			2.5	μA
		$V_R = 25\text{V}$, $T_A = 150^\circ\text{C}$			30	
		$V_R = 70\text{V}$, $T_A = 150^\circ\text{C}$			50	
Diode Capacitance	C_O	$V_R = 0$, $f = 1.0\text{MHz}$			1.5	pF
Reverse Recovery Time	t_{RR}	$I_F = I_R = 10\text{mA}$, $I_{RR} = 1.0\text{mA}$ $R_L = 100\Omega$			6.0	ns

TYPICAL CHARACTERISTICS

Reverse Voltage vs. Reverse Current
BV - 1.0 ~ 100 μ A

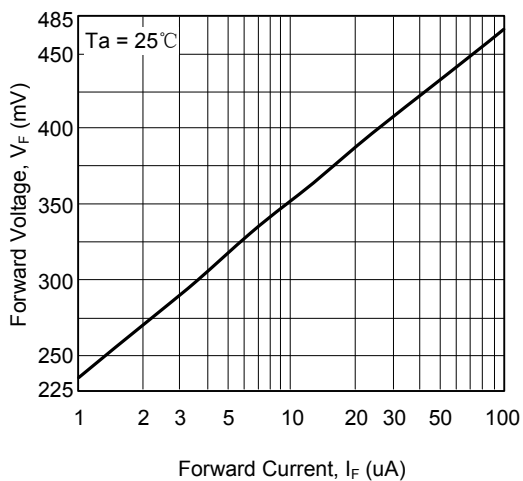


Reverse Current vs. Reverse Voltage
 I_R - 10 ~ 100 V

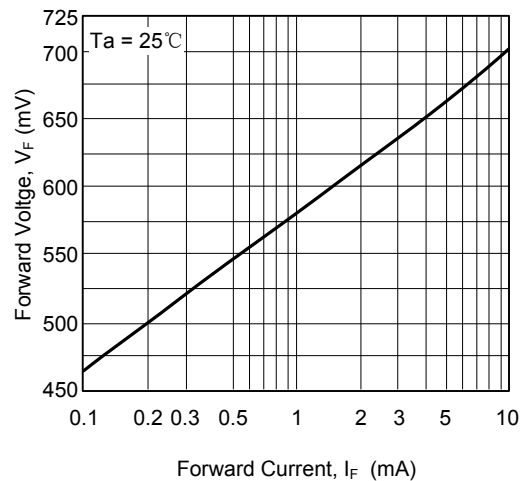


GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

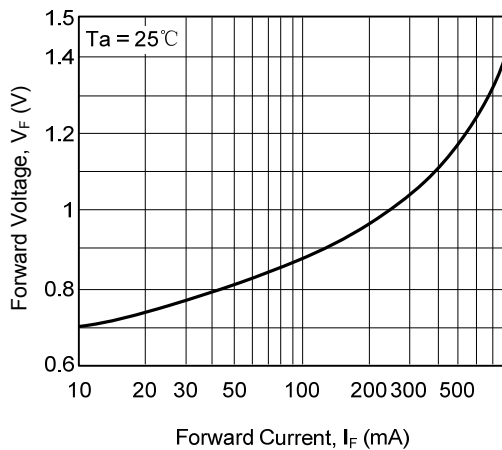
Forward Voltage vs. Forward Current
 V_F - 1.0 ~ 100 μ A



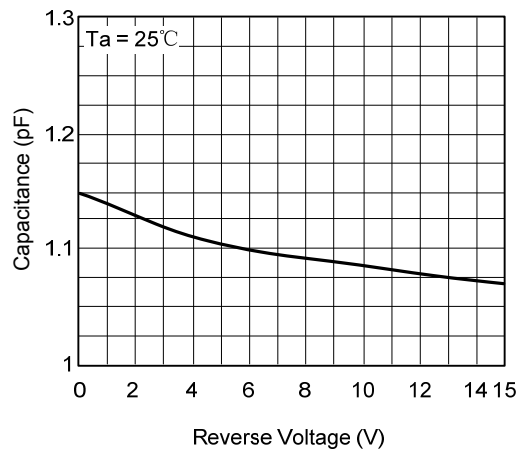
Forward Voltage vs. Forward Current
 V_F - 0.1 ~ 10 mA



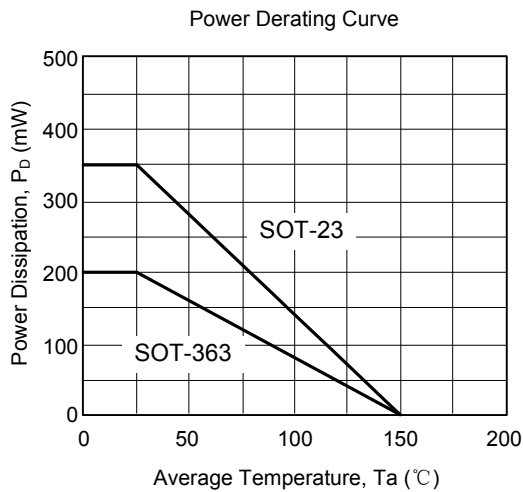
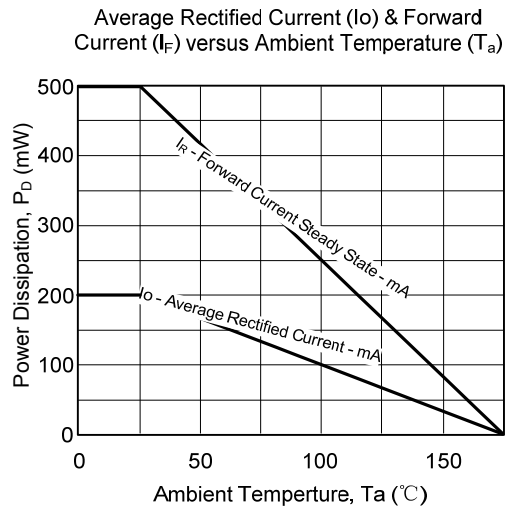
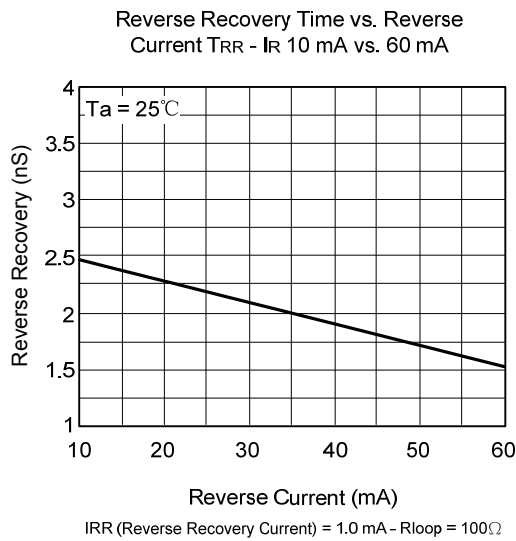
Forward Voltage vs. Forward Current
 V_F - 1.0 ~ 800 mA



Capacitance vs. Reverse Voltage
 V_R - 0.0 ~ 15 V



■ TYPICAL CHARACTERISTICS(Cont.)



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